



MOS FIELD EFFECT TRANSISTOR 2SJ353

P-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

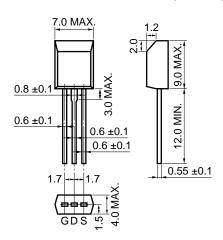
The 2SJ353 is a P-channel MOS FET of a vertical type and is a switching element that can be directly driven by the output of an IC operating at 5 V.

This product has a low ON resistance and superb switching characteristics and is ideal for driving the actuators and DC/DC converters.

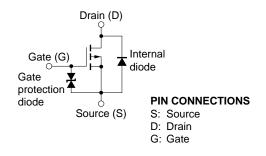
FEATURES

- Radial taping supported
- Can be directly driven by output of 5-V IC
- Low ON resistance $R_{DS(on)} = 0.68 \ \Omega \text{ MAX}.$ @Vgs = -4 V, Ip = -0.8 A $R_{DS(on)} = 0.37 \ \Omega \text{ MAX}.$ @Vgs = -10 V, Ip = -1.0 A

PACKAGE DIMENSIONS (in mm)



EQUIVALENT CIRCUIT



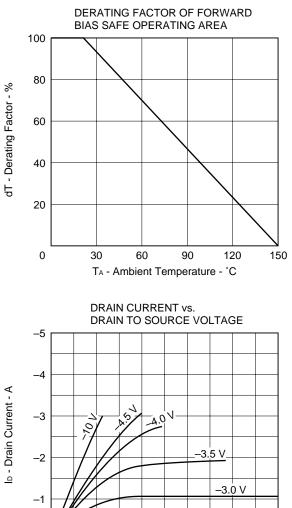
ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

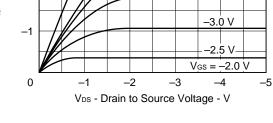
PARAMETER	SYMBOL	TEST CONDITIONS	RATING	UNIT
Drain to Source Voltage	Vdss	Vgs = 0	-60	V
Gate to Source Voltage	Vgss	V _{DS} = 0	±20/+10	V
Drain Current (DC)	ID(DC)		±1.5	А
Drain Current (Pulse)	D(pulse)	PW ≤ 10 ms, Duty cycle ≤ 1 %	±3.0	A
Total Power Dissipation	Рт		1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		–55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

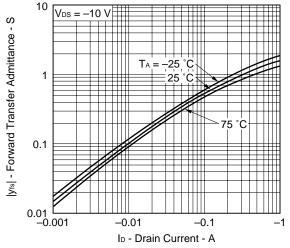
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-Off Current	IDSS	$V_{DS} = -60 V, V_{GS} = 0$			-10	μΑ
Gate Leakage Current	lgss	$V_{GS} = -16/+10 V, V_{DS} = 0$			±10	μΑ
Gate Cut-Off Voltage	VGS(off)	$V_{DS} = -10 V, I_{D} = -1 mA$	-1.0	-1.6	-2.0	V
Forward Transfer Admittance	y _{fs}	$V_{DS} = -10 \text{ V}, \text{ ID} = -1.0 \text{ A}$	1.0			S
Drain to Source On-State Resistance	RDS(on)1	$V_{GS} = -4 V, I_D = -0.8 A$		0.58	0.68	Ω
Drain to Source On-State Resistance	RDS(on)2	$V_{GS} = -10 \text{ V}, \text{ Id} = -1.0 \text{ A}$		0.33	0.37	Ω
Input Capacitance	Ciss	$V_{DS} = -10 V$, $V_{GS} = 0$, f = 1.0 MHz		320		pF
Output Capacitance	Coss			200		pF
Reverse Transfer Capacitance	Crss			70		pF
Turn-On Delay Time	td(on)	$V_{DD} = -30 \text{ V}, \text{ ID} = -1.0 \text{ A}$ $V_{GS(on)} = -10 \text{ V},$ $R_{G} = 10 \Omega, \text{ RL} = 30 \Omega$		5		ns
Rise Time	tr			15		ns
Turn-Off Delay Time	t _{d(off)}			40		ns
Fall Time	tr			20		ns

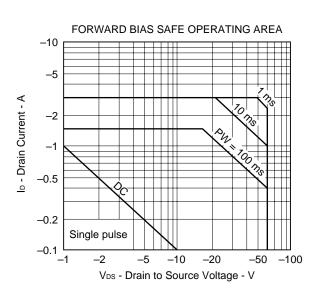




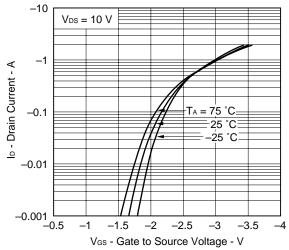




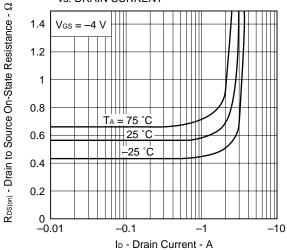


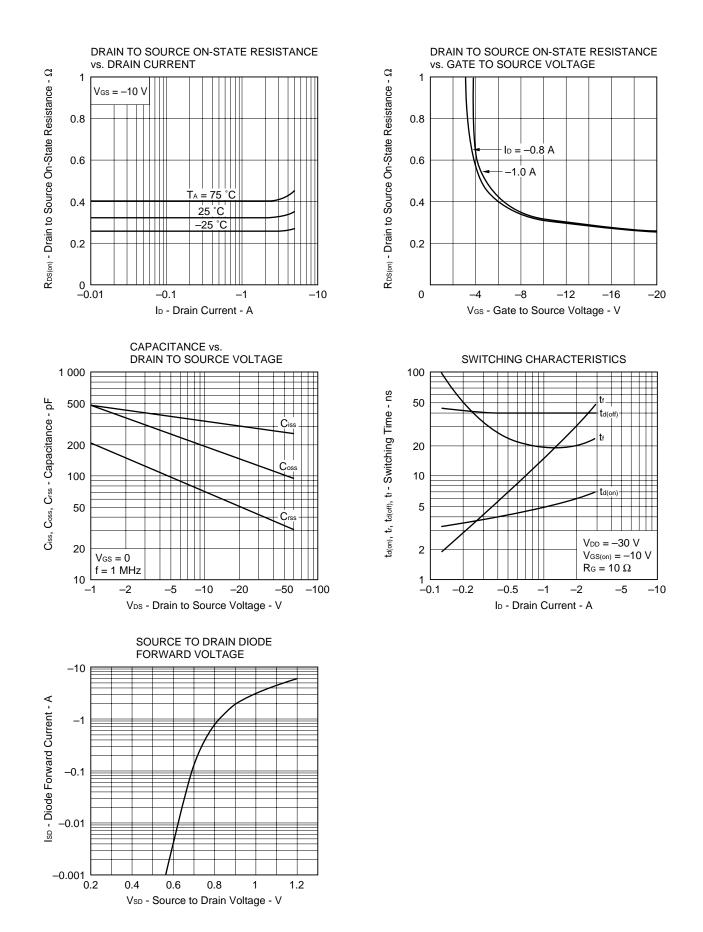


TRANSFER CHARACTERISTICS



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT





REFERENCE

Document Name	Document No.		
NEC semiconductor device reliability/quality control system	TEI-1202		
Quality grade on NEC semiconductor devices	IEI-1209		
Semiconductor device mounting technology manual	C10535E		
Guide to quality assurance for semiconductor devices	MEI-1202		
Semiconductor selection guide	X10679E		

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Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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